NSN 5961-01-344-5688

Unitized Semiconductor Devices - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-344-5688 **Inclosure Material:** Plastic **Overall Length:** Between 0.660 inches and 0.780 inches **Terminal Length:** Between 0.105 inches and 1.550 inches **Overall Height:** 0.180 inches **Overall Width:** Between 0.220 inches and 0.300 inches **End Application:** 1260-01-165-3959 control-display system **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Gold plated leads **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -5.0 emitter to base voltage, static, collector open all transistor and -50.0 collector to emitter voltage/static/base open all transistor and -60.0 collector to base voltage/static/emitter open all transistor **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 700.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 14 pin Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-01-344-5688

Unitized Semiconductor Devices - Page 2 of 2



Fiig:

A110a0